

SOD-323 Schottky Barrier Diode 肖特基势垒二极管**■ Internal Configuration& Device Marking 内部结构与产品打标**

Type 型号	BAS40WS	
Pin 管脚		
Mark 打标	43	

■ Absolute Maximum Ratings 最大额定值

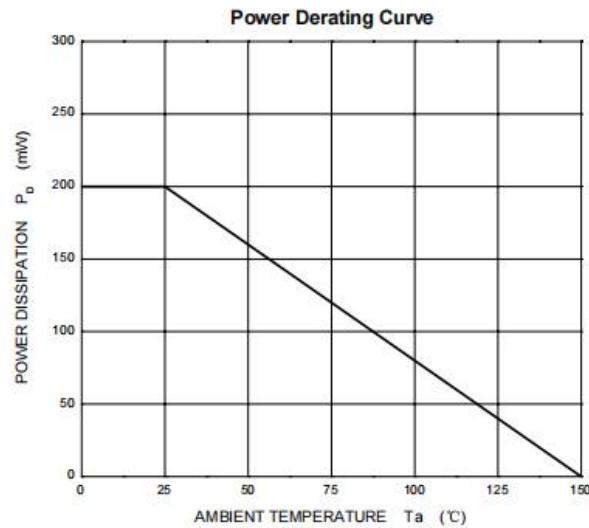
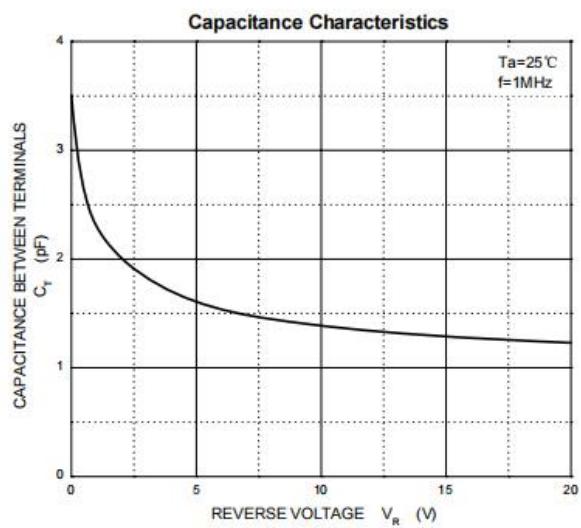
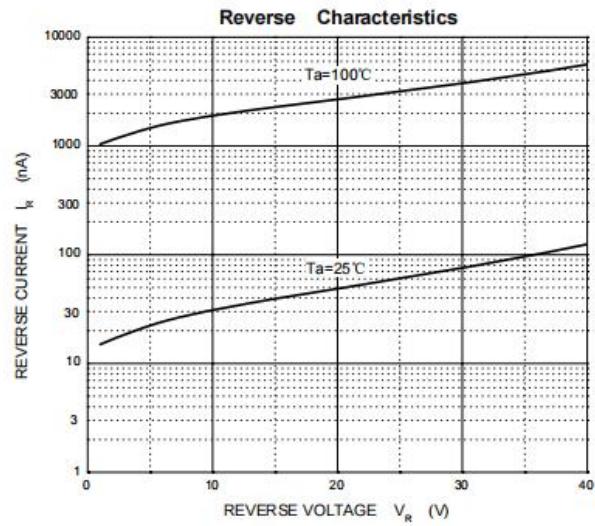
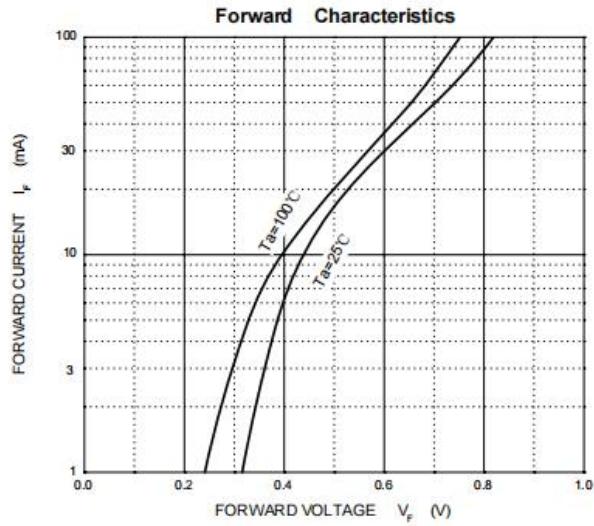
Characteristic 特性参数	Symbol 符号	Rat 额定值	Unit 单位
Peak Reverse Voltage 反向峰值电压	V _{RRM}	40	V
Reverse Work Voltage 反向工作电压	V _{RWM}		
DC Reverse Voltage 直流反向电压	V _R		
Forward Work Current 正向工作电流	I _F (I _O)	200	mA
Peak Surge Forward Current 正向峰值浪涌电流	I _{FSM}	600	mA
Power dissipation 耗散功率	P _D (Ta=25°C)	200	mW
Thermal Resistance J-A 结到环境热阻	R _{θJA}	500	°C/W
Junction and Storage Temperature 结温和储藏温度	T _J , T _{stg}	-55 to +125°C	

■ Electrical Characteristics 电特性

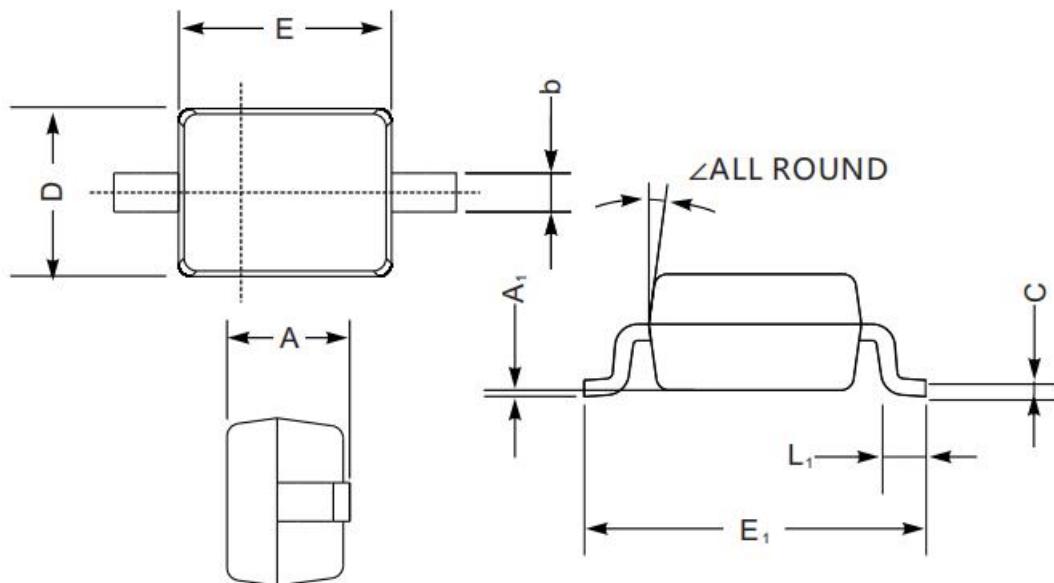
(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	Min 最小值	Max 最大值	Unit 单位
Reverse Breakdown Voltage 反向击穿电压(I _R =10μA)	V _(BR)	40	—	V
Reverse Leakage Current 反向漏电流(V _R =30V)	I _R	—	0.2	μA
Forward Voltage(I _F =1mA) 正向电压(I _F =10mA) (I _F =40mA)	V _F		0.38 0.5 1	V
Diode Capacitance 二极管电容(V _R =0V, f=1MHz)	C _D	—	5	pF
Reverse Recovery Time 反向恢复时间 (I _F =I _R =10mA I _{rr} =0.1XI _R , R _L =100Ω)	T _{rr}	—	5	nS

■Typical Characteristic Curve 典型特性曲线



■Dimension 外形封装尺寸



SOD-323 mechanical data

UNIT		A	C	D	E	E ₁	b	L ₁	A ₁	∠
mm	max	1.1	0.15	1.4	1.8	2.75	0.4	0.45	0.2	9°
	min	0.8	0.08	1.2	1.4	2.55	0.25	0.2	—	
mil	max	43	5.9	55	70	108	16	16	8	9°
	min	32	3.1	47	63	100	9.8	7.9	—	